PA6203

Preliminary

CMOS IC

1.25-W MONO FULLY DIFFERENTIAL AUDIO POWER AMPLIFIER

DESCRIPTION

The UTC **PA6203** is a mono fully-differential audio amplifier, capable of delivering 1.25W of continuous average power to an $8-\Omega$ BTL load with less than 1% distortion from a 5V power supply.

The UTC **PA6203** is ideal for PDA/smart phone applications due to features such as -85-dB supply voltage rejection from 90Hz to 5kHz, improved RF rectification immunity and a fast start-up with minimal pop. The device operates from 2.5V to 5.5V, drawing only 1.7mA of quiescent supply current.

FEATURES

- * 1.25W into 8Ω from a 5-V supply at THD=1% (Typ.)
- * 2.5V-5.5V operation
- * Low supply current: 1.7mA typ at 5V
- * Shutdown Control<10µA
- * Only five external components
 - Improved PSRR (90dB) for direct battery operation
 - Fully differential design reduces RF rectification
 - Improved CMRR eliminates two input coupling capacitors
 - C_(BYPASS) is optional due to fully differential design and high PSRR

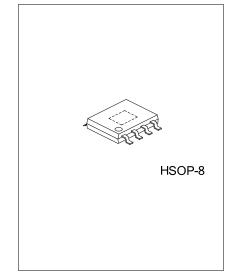
APPLICATIONS

* Designed for wireless or cellular handsets and PDAs

ORDERING INFORMATION

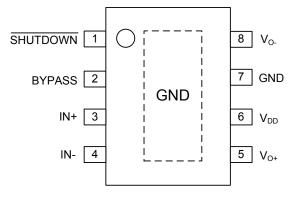
Ordering	Number	Deekeese	Decking
Lead Free	Halogen Free	Package	Packing
PA6203L-SH2-T	PA6203G-SH2-T	HSOP-8	Tube
PA6203L-SH2-R	PA6203G-SH2-R	HSOP-8	Tape Reel

РА6203 <u></u> - <u>S</u> H2- <u>Т</u>	
(1)Packing Type	(1) T: Tube, R: Tape Reel
(2)Package Type	(2) SH2: HSOP-8
(3)Halogen Free	(3) L: Lead Free, G: Halogen Free



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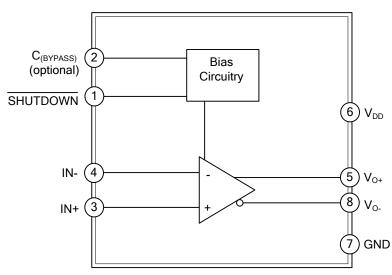
PIN CONFIGURATION



PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	SHUTDOWN	Shutdown terminal (active low logic)
2	BYPASS	Mid-supply voltage, adding a bypass capacitor improves PSRR
3	IN+	Positive differential input
4	IN-	Negative differential input
5	V _{O+}	Positive BTL output
6	V _{DD}	Supply voltage terminal
7	GND	High-current ground
8	Vo-	Negative BTL output
	Thermal Pad	Connect to ground. Thermal Pad must be soldered down in all applications to properly secure device on the PCB.

BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATING (Over operating free-air temperature range, unless otherwise noted)

P	ARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage		V _{DD}	-0.3~6	V
Input Voltage INx and SHUTDOWN Pins		VI	-0.3~V _{DD} +0.3	V
Continuous Total Power Dissipation		PD	Internally Limited	
Operating Free-air Temperature		T _A	-40~85	°C
Junction Temperature		TJ	-40~125	°C
Storage Temperature		T _{STG}	-65~150	°C
Lead Temperature From Case For 10 Seconds			260	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ _{JA}	42.3	°C/W
Junction to Case	θ _{JC}	12	°C/W

RECOMMENDED OPERATING CONDITIONS

PACKAGE	SYMBOL	MIN	TYP	MAX	UNIT	
Supply Voltage		V _{DD}	2.5		5.5	V
High-Level Input Voltage	SHUTDOWN	V _{IH}	2			V
Low-Level Input Voltage	SHUTDOWN	V _{IL}			0.8	V
Common-Mode Input Voltage	V=2.5V, 5.5V, CMRR≤-60dB	V _{IC}	0.5		V _{DD} -0.8	V
Operating Free-Air Temperature		T _A	-40		85	°C
Load Impedance		ZL	6.4	8		Ω

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, Gain=1V/V, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDIT	IONS	MIN	TYP	MAX	UNIT
Output Offset Voltage (Measured Differentially)	V ₀₀	V _I =0V, V _{DD} =2.5V~5.5V				9	mV
Power Supply Rejection Radio	PSRR	V _{DD} =2.5V~5.5V			-90	-70	dB
Common Mode Rejection Ratio	CMRR	V _{DD} =3.6V~5.5V, V _{IC} =0.5V~V _{DD} -0.8			-70	-65	dB
		V _{DD} =2.5V, V _{IC} =0.5V	~1.7V		-62	-55	
		$R_L=8\Omega, V_{IN+}=V_{DD},$	V _{DD} =5.5V		0.30	0.46	
Low-Level Output Voltage	V _{OL}	$V_{IN}=0V \text{ or } V_{IN}=0V,$	V _{DD} =3.6V		0.22		V
		V _{IN-} =V _{DD}	V _{DD} =2.5V		0.19	0.26	
		$R_L=8\Omega$, $V_{IN+}=V_{DD}$,	V _{DD} =5.5V	4.8	5.12		
High-Level Output Voltage	V _{OH}	$V_{IN}=0V \text{ or } V_{IN}=0V,$	V _{DD} =3.6V		3.28		V
		V _{IN-} =V _{DD}	V _{DD} =2.5V	2.1	2.24		
High-Level Input Current	I _{IH}	V _{DD} =5.5V, V _I =5.8V				1.2	μA
Low-Level Input Current	I _{IL}	V _{DD} =5.5V, V _I =-0.3V				1.2	μA
Supply Current	I _{DD}	SHUTDOWN=2V, V _{DD} =2.5V~5.5V, No Load			1.7	2	mA
Supply Current in Shutdown Mode	I _{DD(SD)}	SHUTDOWN=0.8V, V _{DD} =2.5V~5.5V, No	Load		0.01	0.9	μA

■ **OPERATING CHARACTERISTICS** (T_A=25°C, Gain=1V/V, R_L=8Ω)

PARAMETER	SYMBOL	TEST CONDIT	IONS	MIN	TYP	MAX	UNIT	
			V _{DD} =5V		1.25		W	
Output Power	Po	THD+N=1%, f=1kHz	V _{DD} =3.6V		0.63		W	
			V _{DD} =2.5V		0.3		W	
Total Harmonic Distortion Plus		V _{DD} =5V, P _O =1W, f=1kHz			0.06			
Noise	THD+N	V _{DD} =3.6V, P _O =0.5W, f=1kH	Z		0.07		%	
		V _{DD} =2.5V, P _O =200mW, f=1I	kHz		0.08			
		$C_{(BYPASS)}=0.47\mu F$, $V_{DD}=3.6V\sim5.5V$, Inputs Ac-Grounded with $C_I=2\mu F$	f=217Hz~2kHz, V _{RIPPLE} =200mV _{PP}		-87		dB	
Supply Ripple Rejection Ratio	K _{SVR}	$C_{(BYPASS)}=0.47\mu F$, $V_{DD}=2.5V~3.6V$, Inputs Ac-Grounded with $C_1=2\mu F$	f=217Hz~2kHz, V _{RIPPLE} =200mV _{PP}		-82		dB	
		$C_{(BYPASS)}=0.47\mu F$, $V_{DD}=2.5V\sim5.5V$, Inputs Ac-Grounded with $C_{I}=2\mu F$	f=40Hz~20kHz, V _{RIPPLE} =200mV _{PP}		≤-74		dB	
Signal-To-Noise Radio	SNR	V _{DD} =5V, P _O =1W			104		dB	
	V	f=20Hz~20kHz	No Weighting		17			
Output Voltage Noise	V _N		A Weighting		13		μV _{RMS}	
Common Mode Rejection		V _{DD} =2.5V~5.5V, Resistor	f=20Hz~1kHz		≤-85		dB	
Radio	CMRR	Tolerance=0.1%, Gain=4V/V, V _{ICM} =200mV _{PP}	f=20Hz~20kHz		≤-74		dB	
Input Impedance	Zı				2		MΩ	
Output Impedance	Zo	Shutdown Mode		>10k				
Shutdown Attenuation		f=20Hz~20kHz, R _F =R _I =20kΩ			-80		dB	

TYPICAL APPLICATION CIRCUIT

Table 1.	Typical	Component	Values
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COMPONENT	VALUE	UNIT
R	10	kΩ
R _F	10	kΩ
C _(BYPASS) (Note 1)	0.22	μF
Cs	1	μF
C	0.22	μF

Note: 1. $C_{(BYPASS)}$ is optional

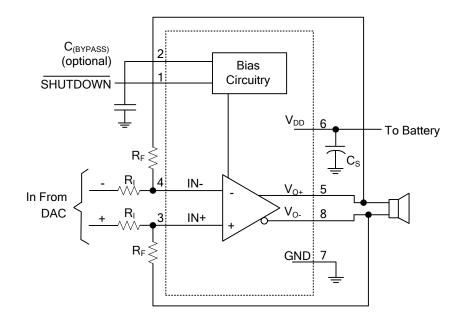


Figure 1. Typical Differential Input Application Schematic

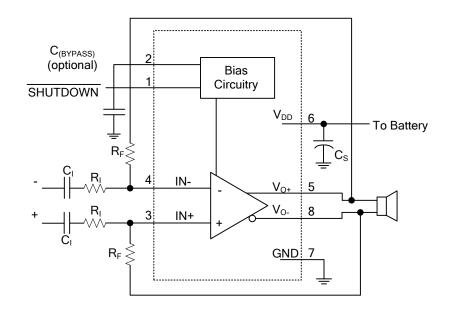


Figure 2. Differential Input Application Schematic Optimized With Input Capacitors

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TYPICAL APPLICATION CIRCUIT(Cont.)

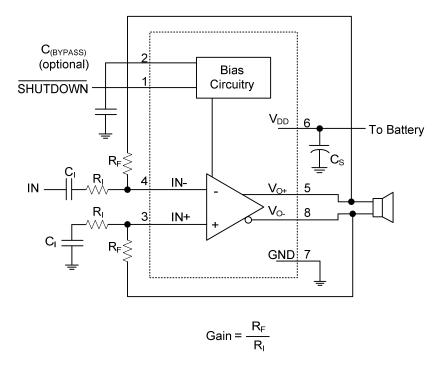


Figure 3. Single-Ended Input Application Schematic